



Elettra Sincrotrone Trieste

# Optical properties of nickelate heterostructures

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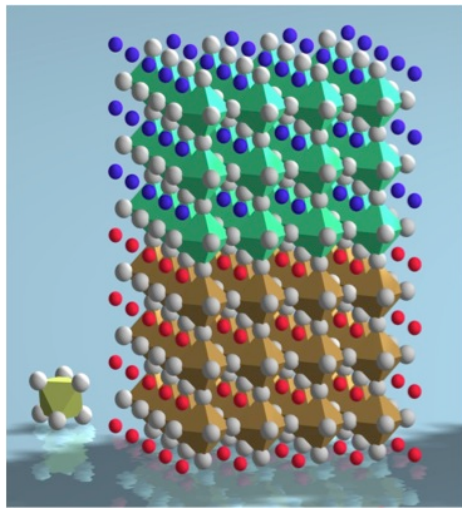
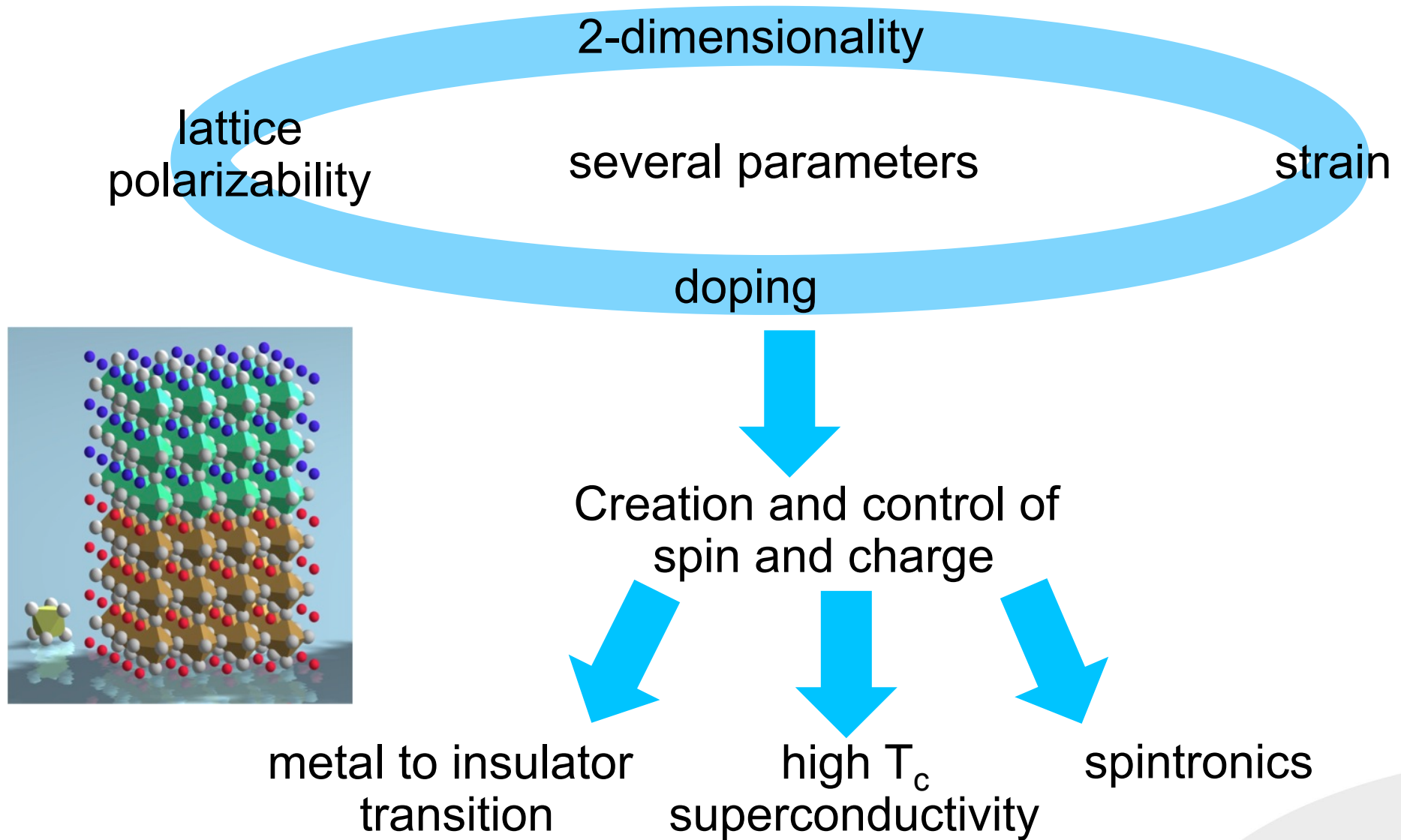


TeraFERMI

SISSI



# Oxide heterostructures

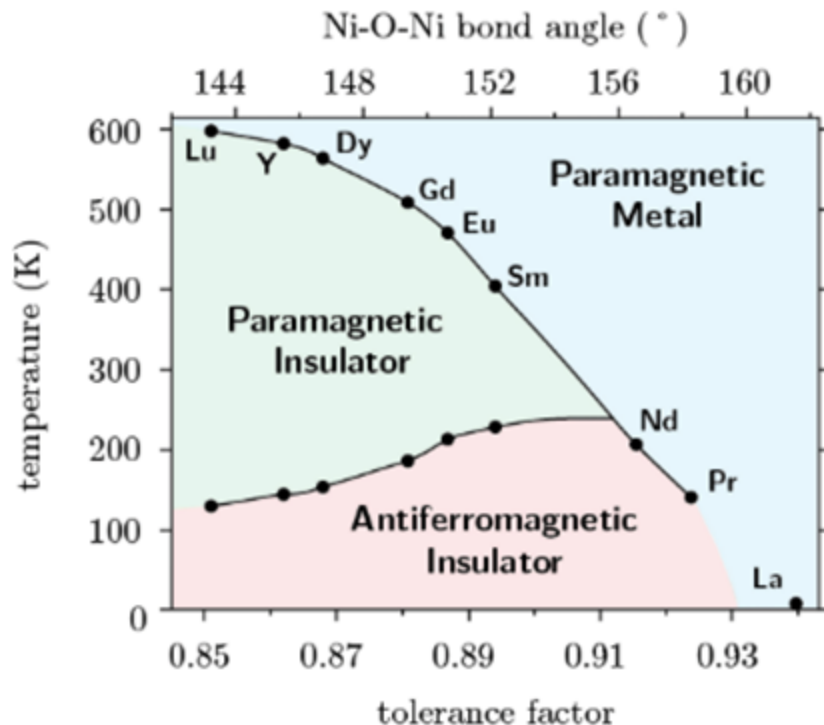


# Motivation: nickelate $\text{LaNiO}_3$

$\text{LaNiO}_3$  is the only nickelate that does not undergo a metal to insulator transition



It does not exhibit a AF-insulating ground state!



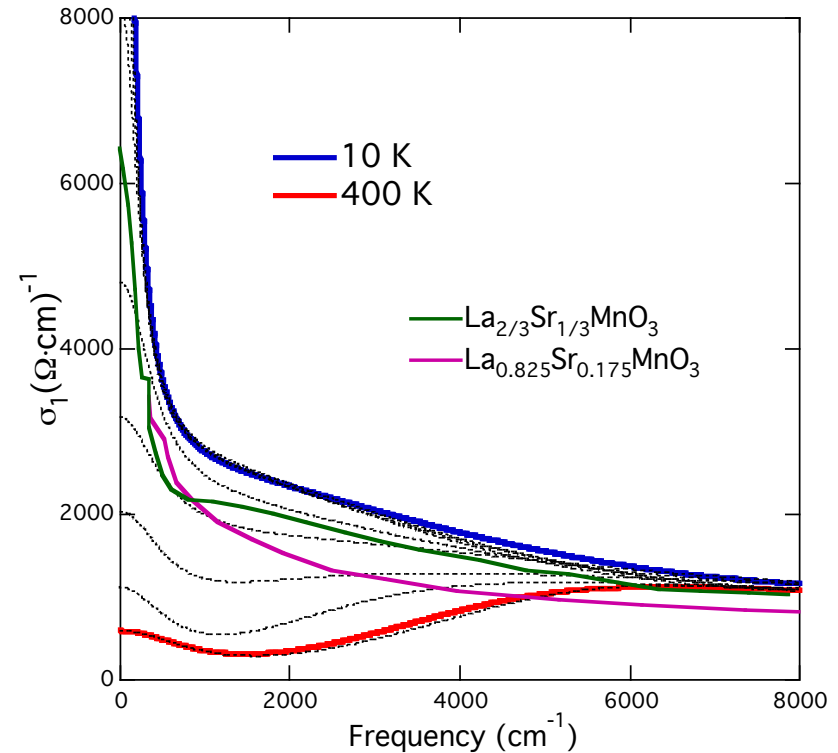
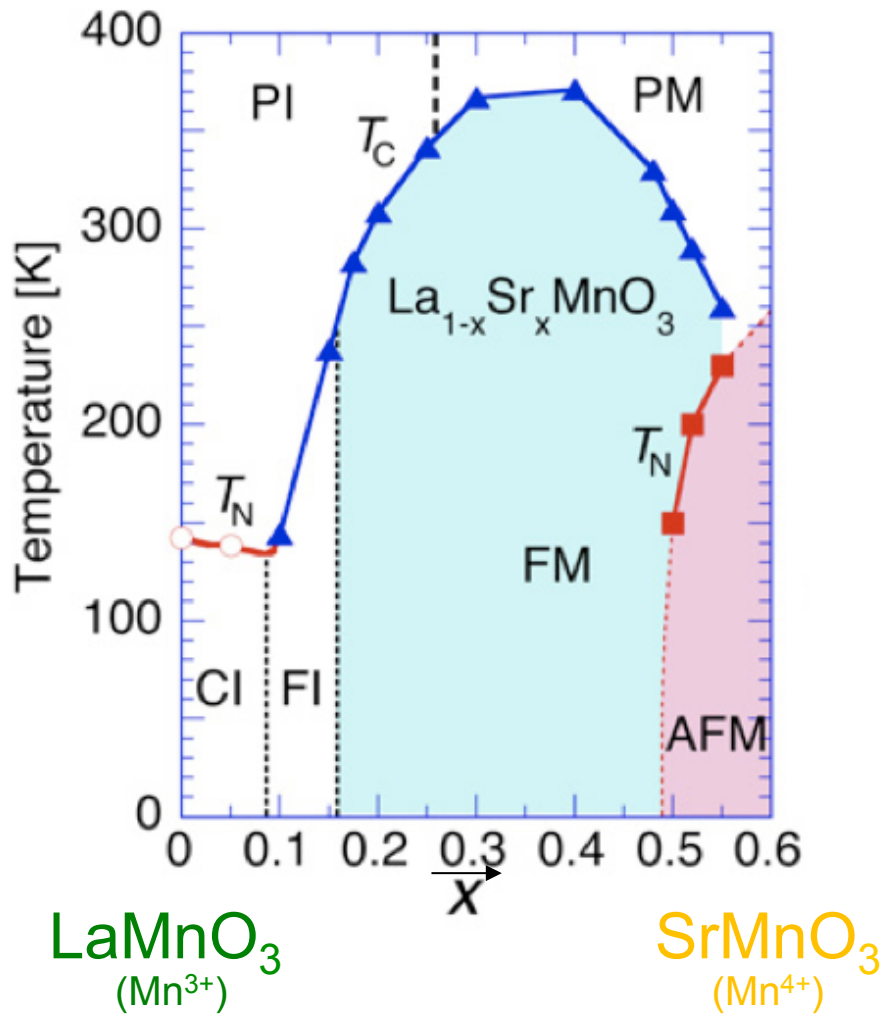
## Controlling the $\text{LaNiO}_3$ ground state with

- ✓ Interfacial doping (**LNO/LMO**)
- ✓ Dimensionality (**LNO/LAO**)
- ✓ THz light (opportunities @TeraFERMI)



$(\text{LaNiO}_3)_n/(\text{LaMnO}_3)_2$   
superlattices  
 $n=2,3,4,5$

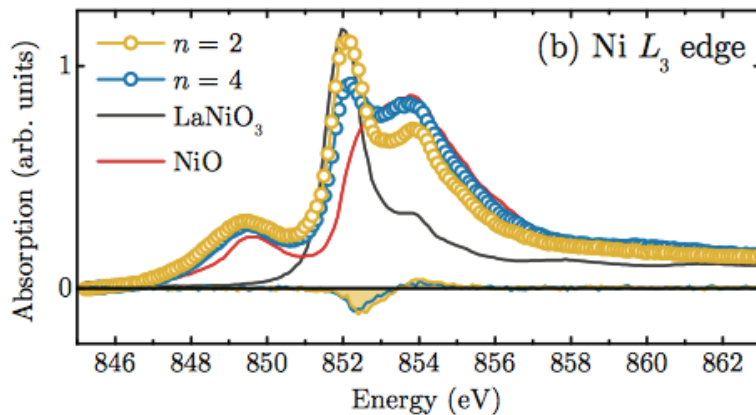
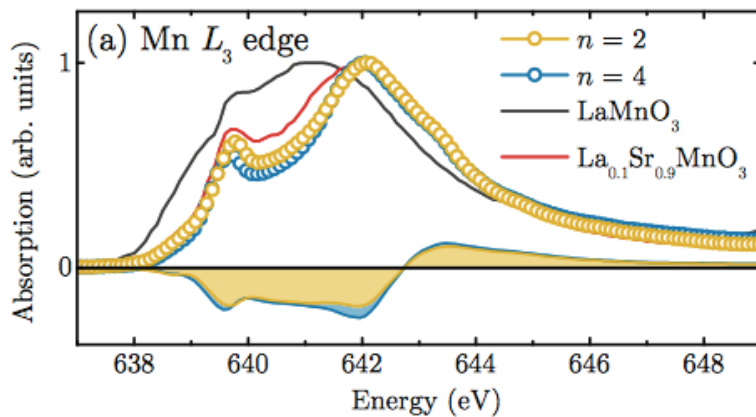
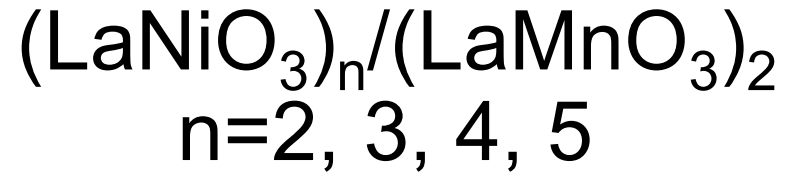
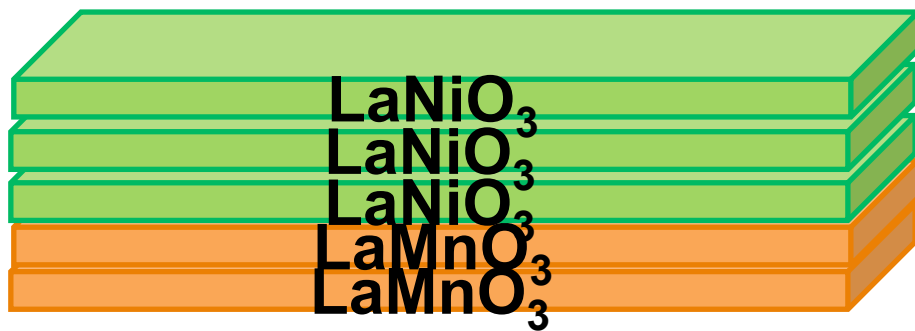
# Interfacial doping: the case of LMO/SMO



Perucchi et al., Nano Letters 2010

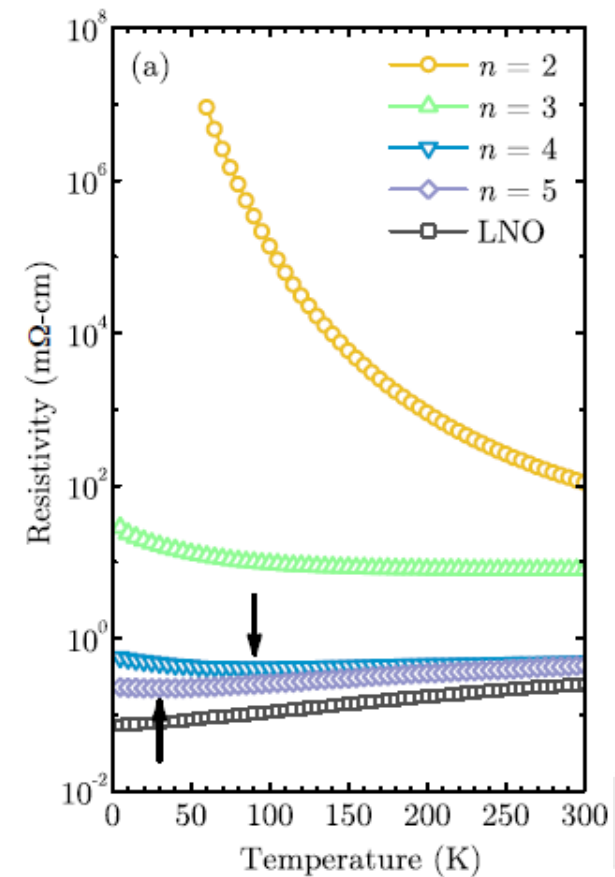
The electronic properties of  $(LMO)_2/(SMO)_1$  SL are fully equivalent to those of the corresponding alloy  $La_{2/3}Sr_{1/3}MnO_3$

# LNO/LMO superlattice



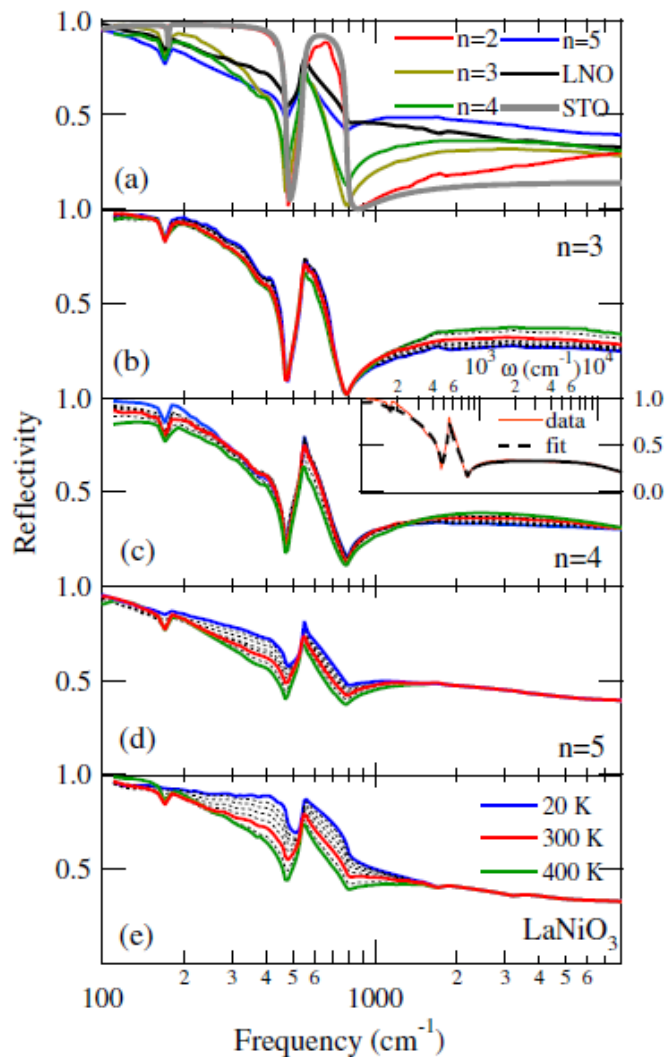
With increasing  $\text{LaNiO}_3$  thickness, the SLs undergo an **insulator-to metal transition**

**X-ray spectroscopy** of this system shows that the Mn oxidation state is converted from 3+ to 4+, while Ni is intermediate between 2+ and 3+

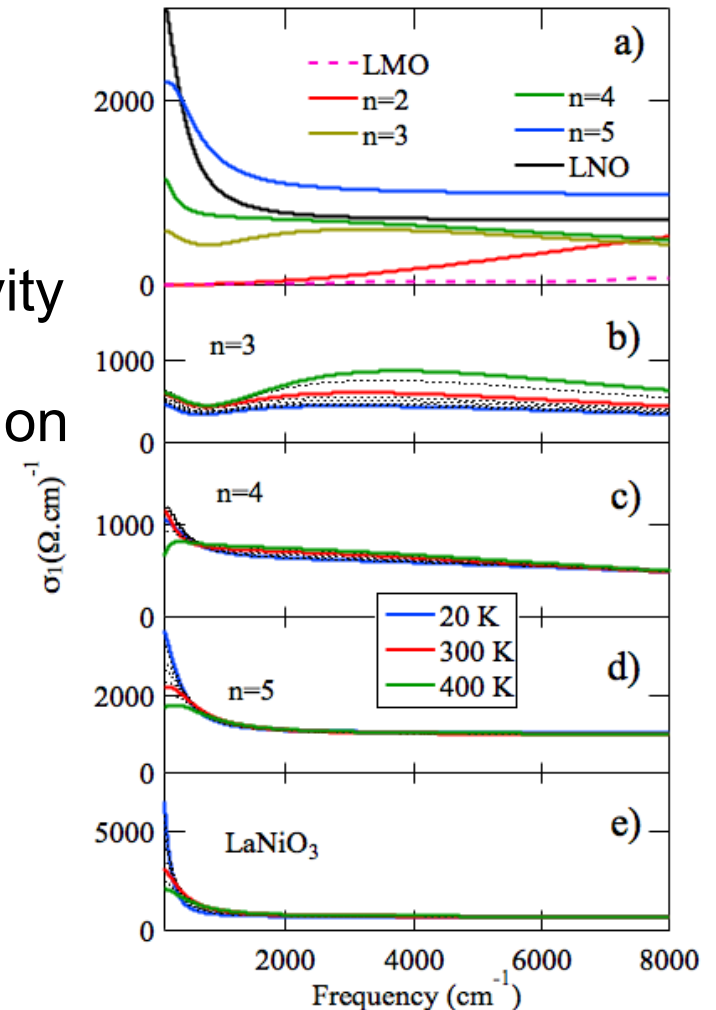


Hoffman et al., Phys Rev B 2013

# Reflectivity and Optical Conductivity



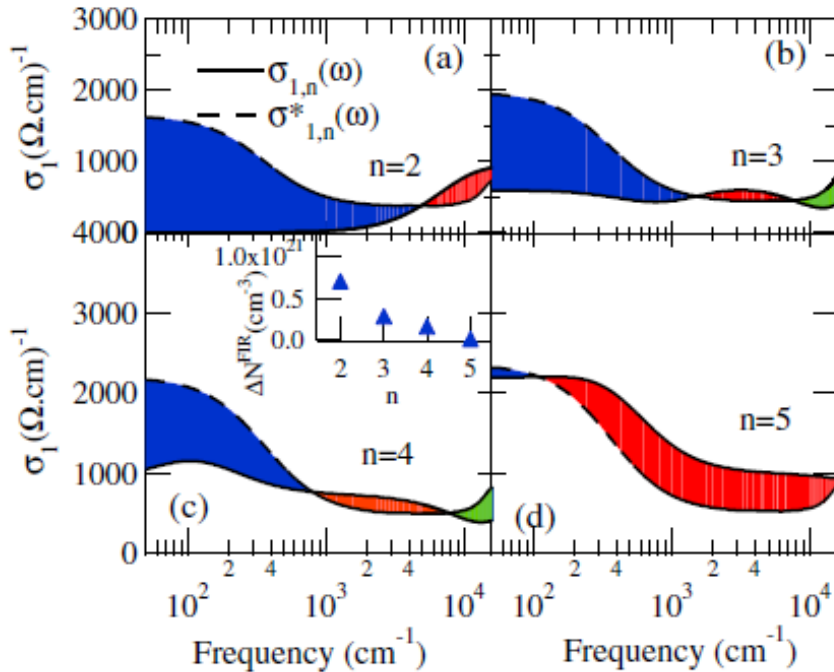
as  $n$  increases:  
the optical conductivity  
increases:  
onset of a metallization



Di Pietro et al., Phys Rev Lett 2015



# Average Optical Conductivity



$$\sigma_{1,n}^* = \frac{n\sigma_{1,\text{LNO}} + 2\sigma_{1,\text{LMO}}}{n+2}$$

The comparison between  $\sigma_{1,n}^*$  and  $\sigma_{1,n}$  allows us to single out the features directly related to the **interfaces**

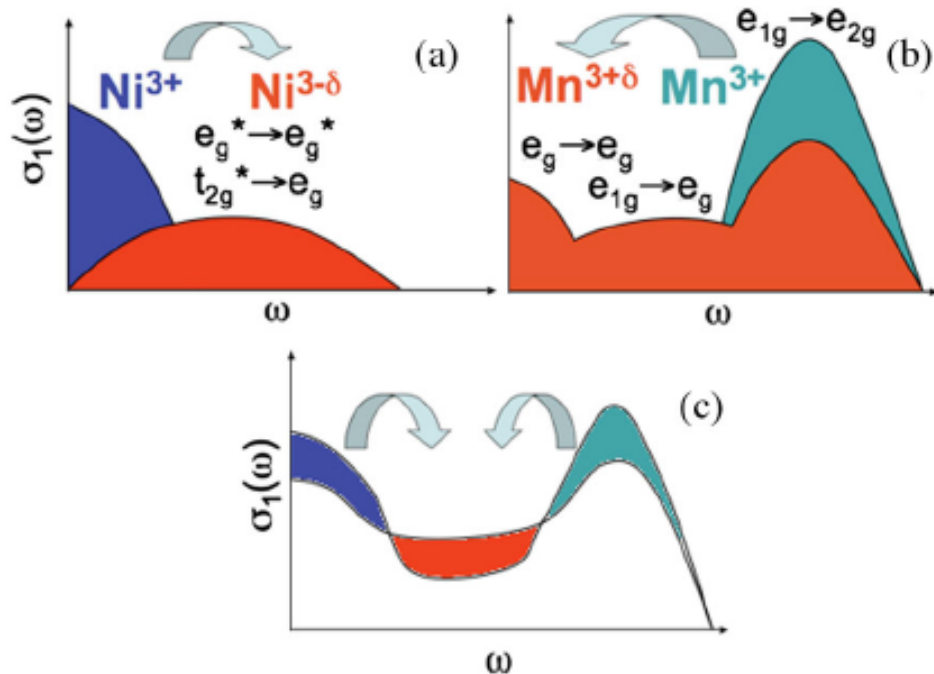
The **red area** is always larger than the **blue area**



The additional MIR spectral weight is only in part due to the loss of SW at low frequencies, and a redistribution from the **green area** is also at play

Di Pietro et al., Phys Rev Lett 2015

# Average Optical Conductivity



In the SLs the valence of **Ni** decreases from its nominal Ni 3+ value, as n decreases



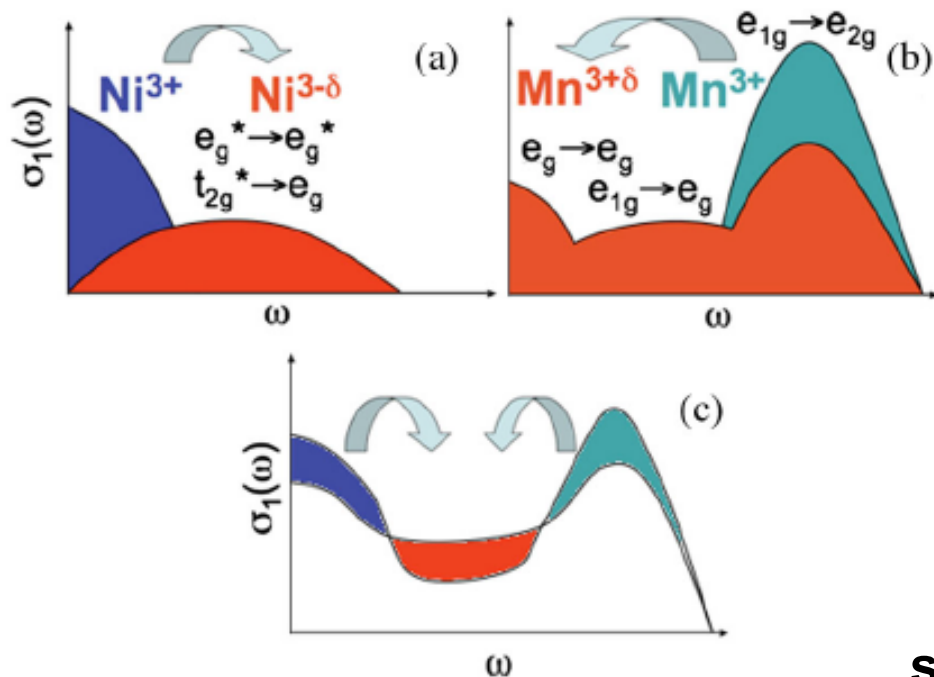
MIT at Ni valence 2.75

In the SLs **Mn** valence increases from 3+ to a higher value: polaronic states appear in the MIR, whose SW is taken from the Jahn-Teller band at 2.5 eV

introduction of LMO layers in the SL, by reducing the Ni valence, progressively depletes the low energy, coherent SW of LNO, which piles up in the infrared at expenses of FIR and VIS/UV

Di Pietro et al., Phys Rev Lett 2015

# Average Optical Conductivity



Infrared data show that the LNO/LMO SLs display the presence of significant midinfrared excitations that are not present in LNO or LMO alone.

**Interfacial charge redistribution is identified as the origin of changes to the MIR spectral response.**

This is in contrast to what is observed in **ultrathin LNO films** and in **LNO/LAO superlattices**, where localization is believed to occur due to dimensional confinement and enhanced correlations...

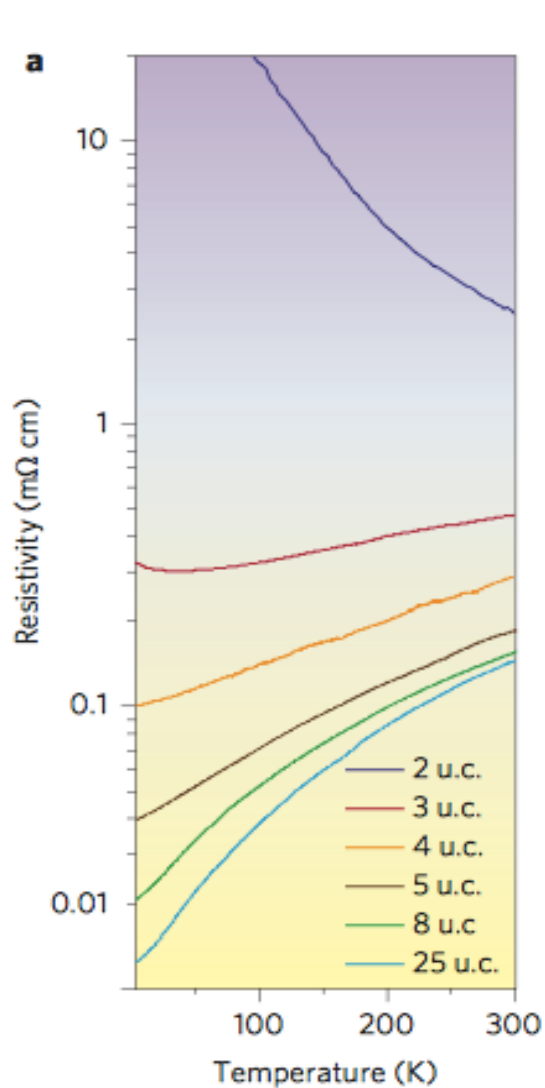
Di Pietro et al., Phys Rev Lett 2015



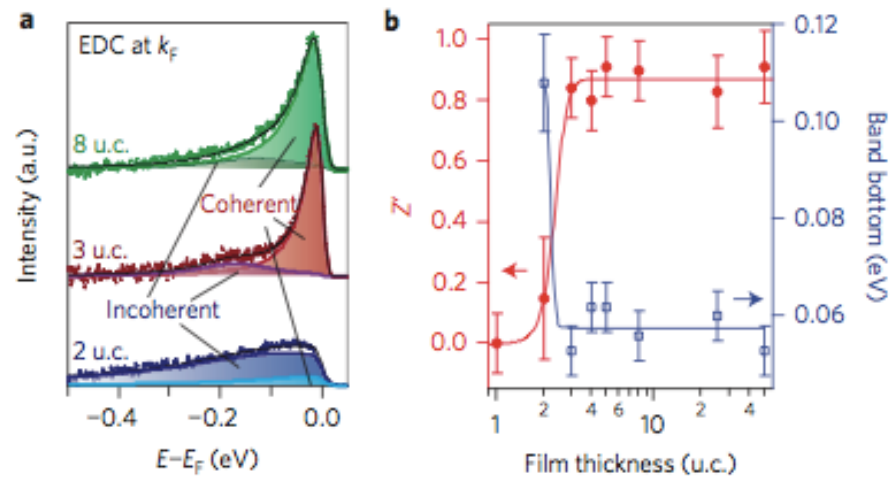
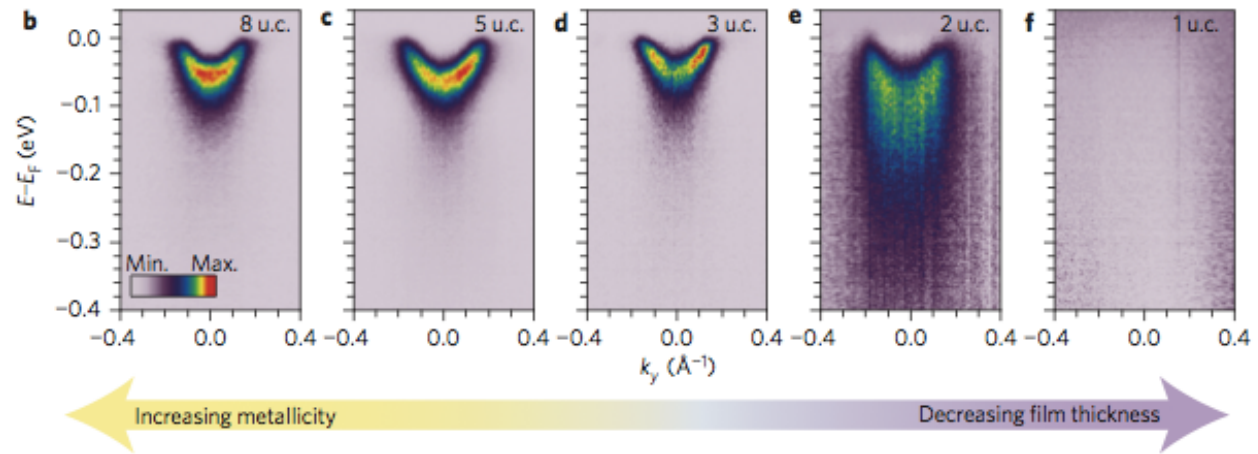
# (LaNiO<sub>3</sub>) thin films and (LaNiO<sub>3</sub>) / (LaAlO<sub>3</sub>) superlattice



# ARPES results on LNO thin films

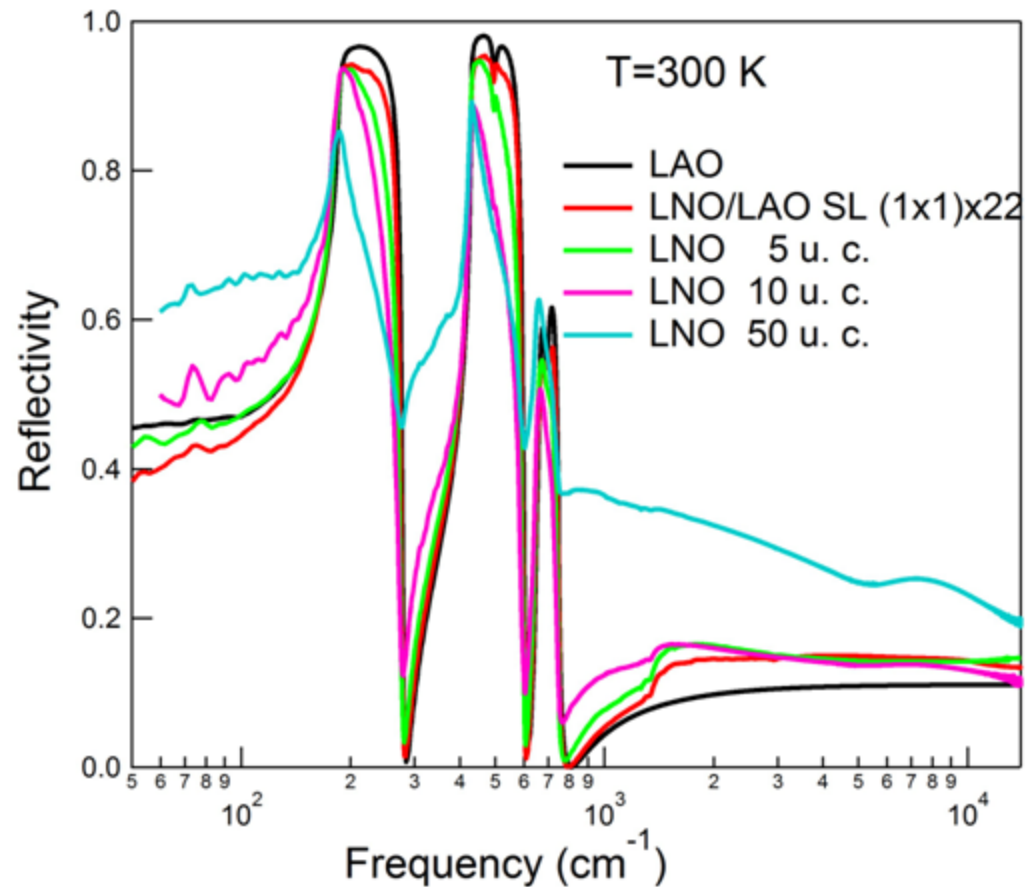


King et al., Nature Nano 2014



abrupt destruction of Fermi liquid-like quasiparticles in the correlated metal LNO when confined to a critical film thickness of 2 unit cells

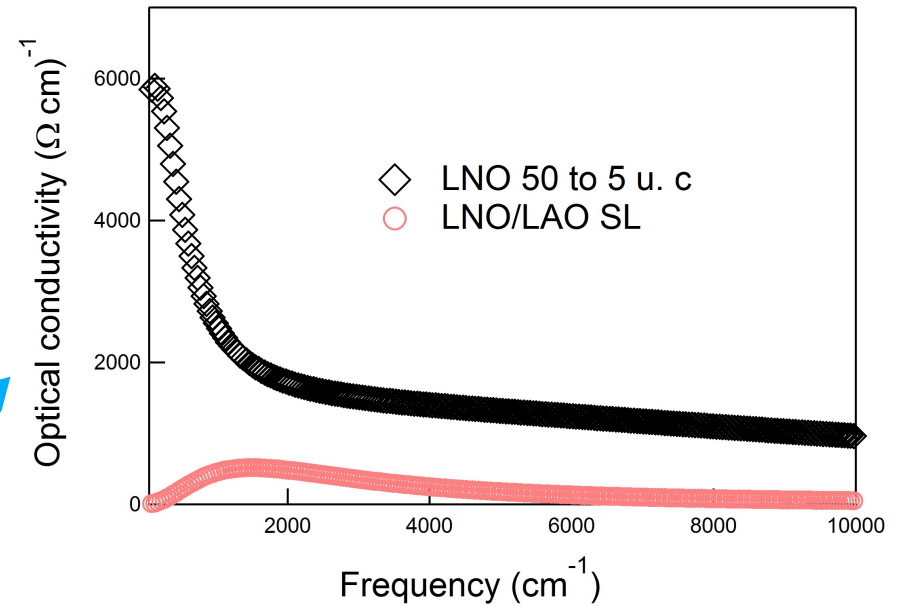
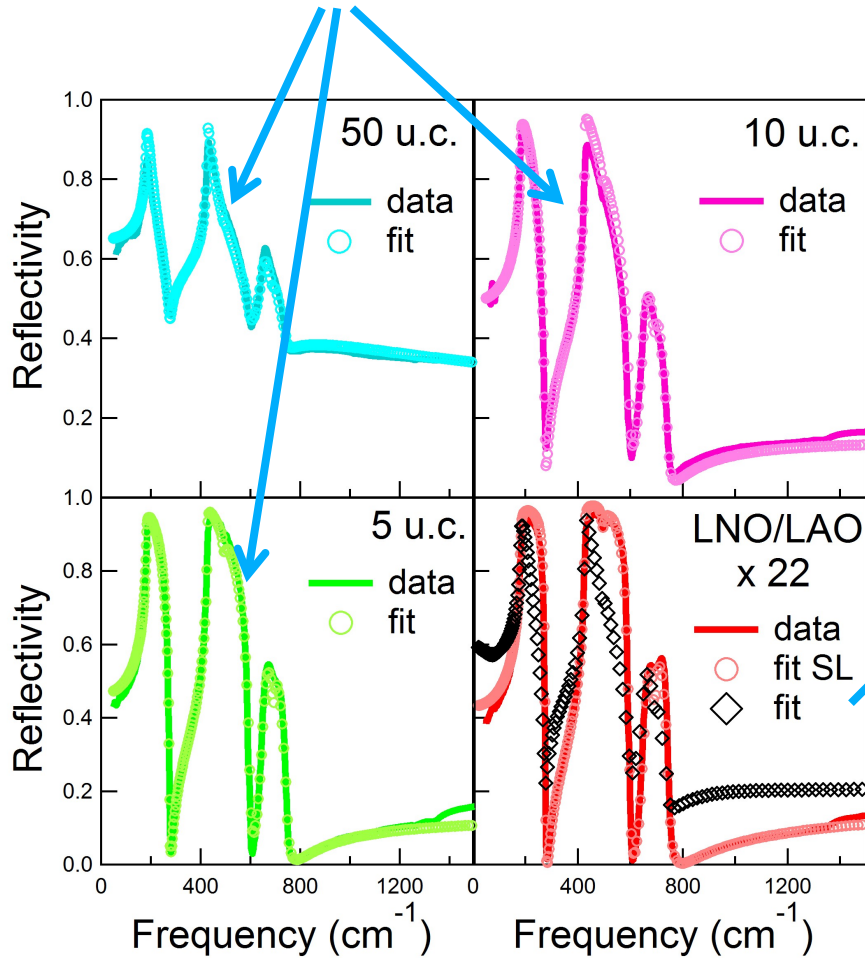
# LNO thin films and LNO/LAO SL: reflectivities



Fitting this data to a Drude-Lorentz model we can show the effect of the thickness in LNO....

T=300 K

**Same Drude-Lorentz parameters!**

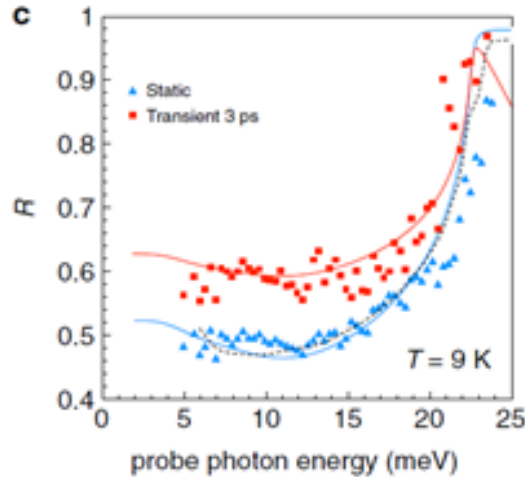
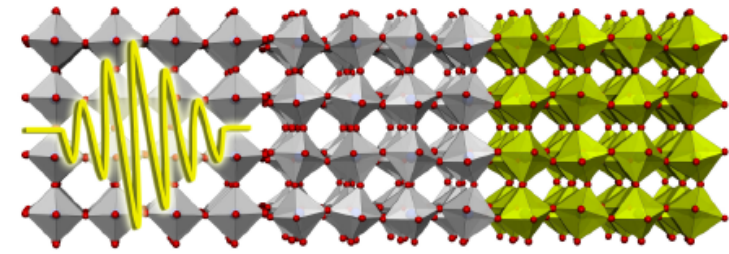


# THz control in Nickelate heterostructure

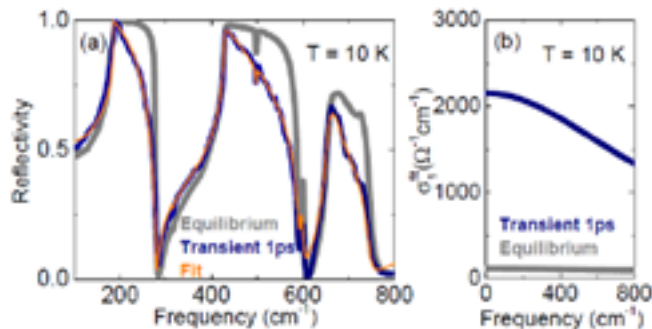




# THz-induced MIT



Cavaglia et al., Phys Rev Lett 2012



Hu et al., arXiv 2016

**Nickelates**  
are very sensitive to **strain**  
due to different substrates



a MIT transition in **NdNiO<sub>3</sub>** and **SmNiO<sub>3</sub>** is  
induced by pumping on the lattice  
of the **LAO** substrate

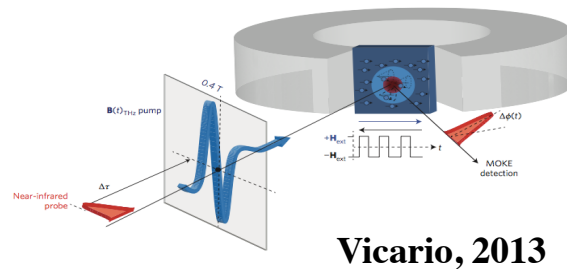
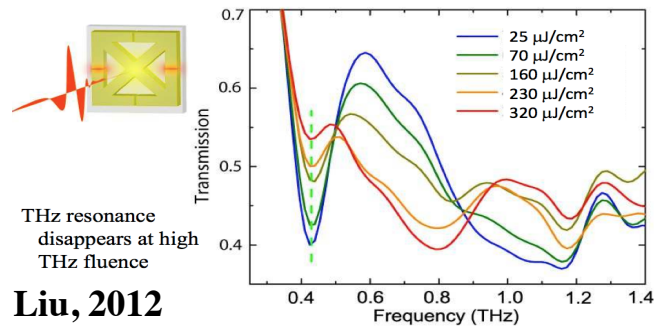
**Exploiting all available phonon  
modes (substrate + film)  
to induce the MIT!**



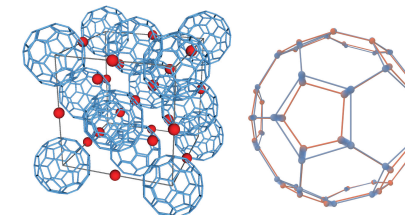
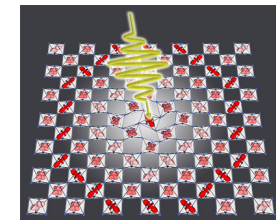
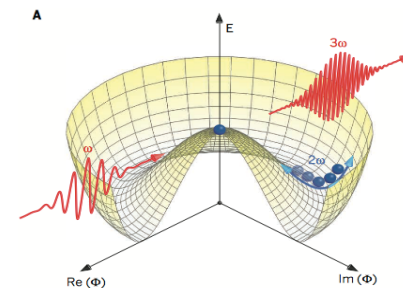
# The TeraFERMI beamline

## THz light couples with electronic, vibrational and magnetic excitations

### *Giant quasi-static fields*



### *Resonant excitations*

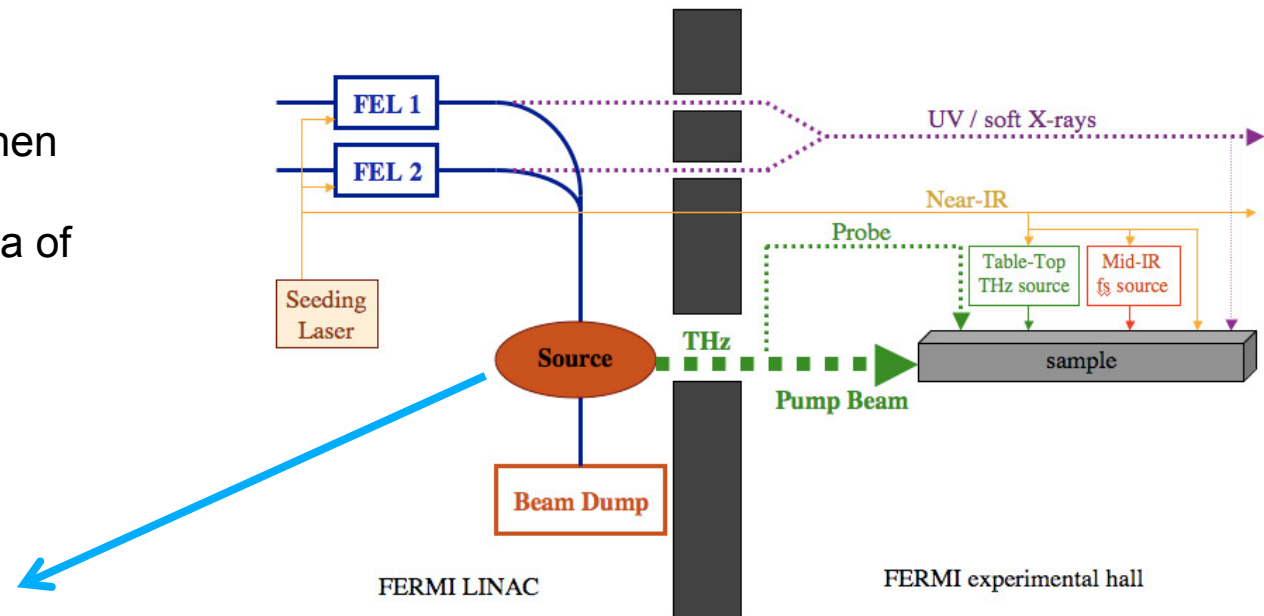
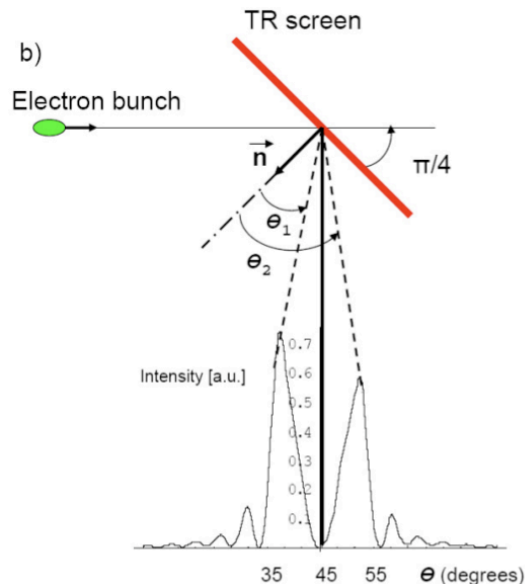


# The TeraFERMI idea

Exploiting the properties of the FERMI-FEL electron beam to produce **Short (sub-ps), Powerful (>MV/cm), Broadband (0.1-15 THz)** THz pulses

to be used as a **Pump** beam for *ultrafast nonlinear spectroscopies*

**Transition Radiation** occurs when relativistic electrons cross the boundary between two media of different dielectric constant



TeraFERMI will not affect overall FEL available beamtime:  
**THz light always available**  
 Possibility for THz pump / FEL probe



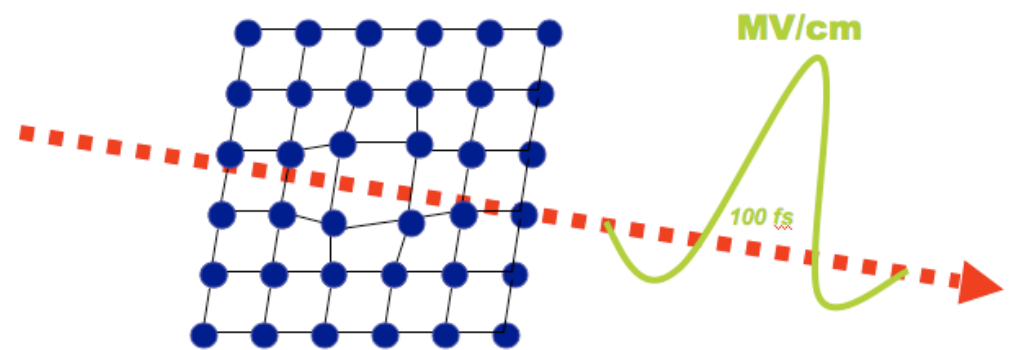
# Beamline parameters

**Ultra-short, high-power THz pulses between 1 mm - 20  $\mu\text{m}$  (0.1 -15 THz)**

*Access to the Reststrahlen-band gap!*

Pumping on electronic, vibrational, magnetic excitations

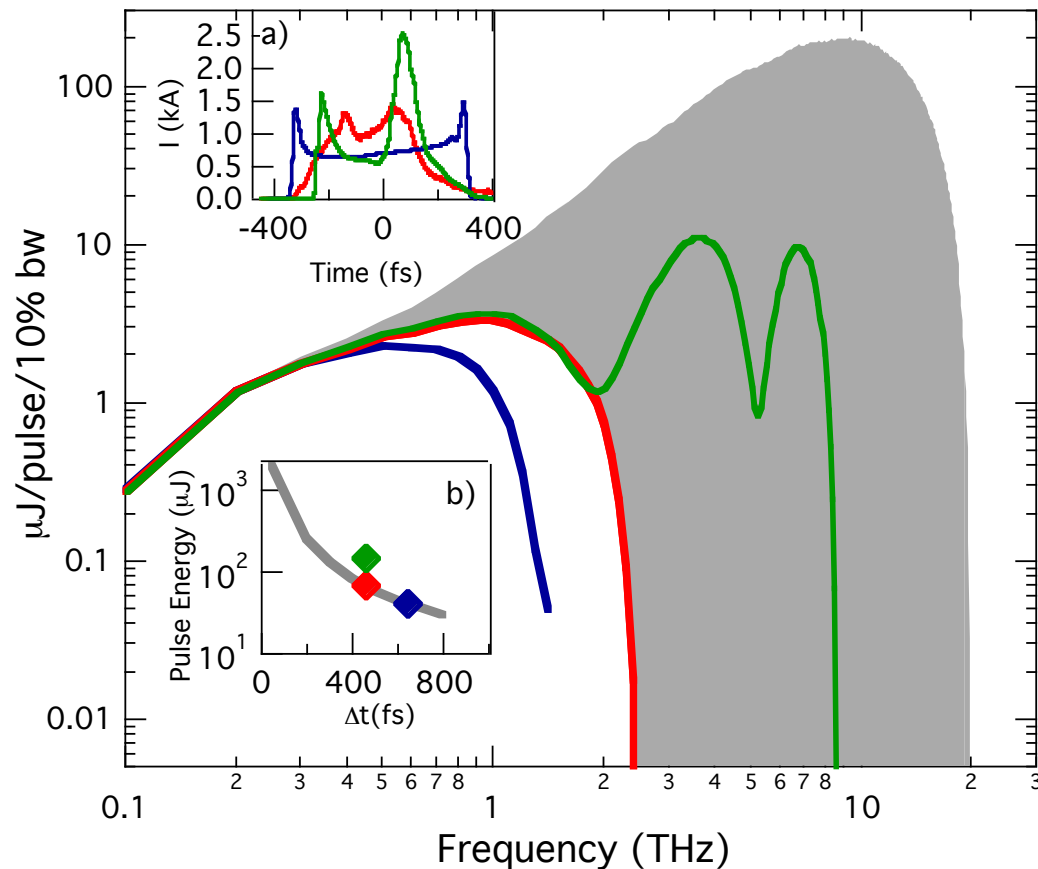
Wavelength range	3 mm - 20 $\mu\text{m}$ (0.1 - 15 THz)
THz pulse energy	50 $\mu\text{J}$ - mJ
Operation Conditions	0.9-1.5 GeV FEL1/FEL2 10 - 50 Hz 700 pC



**FEL1: 65-20 nm**

**FEL2: 20-4 nm**

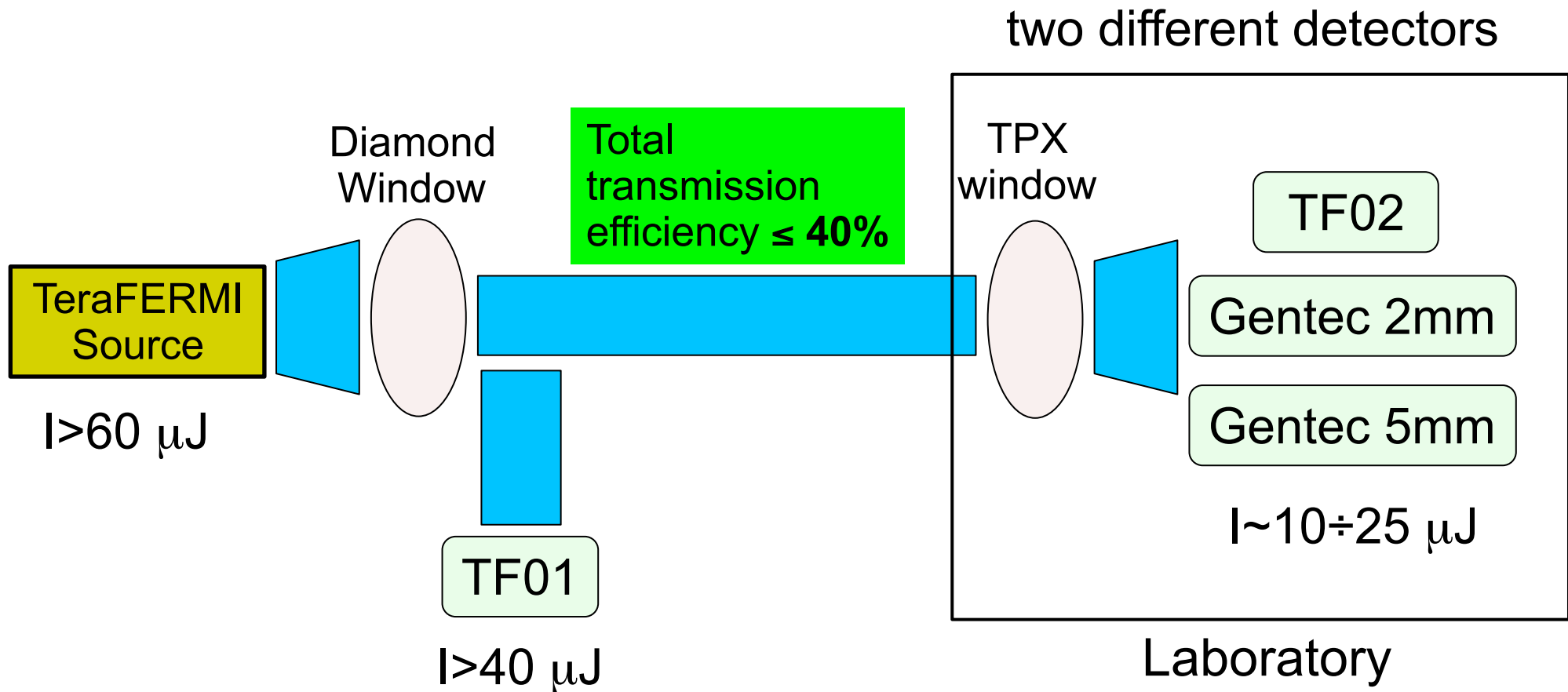
## Expected performances



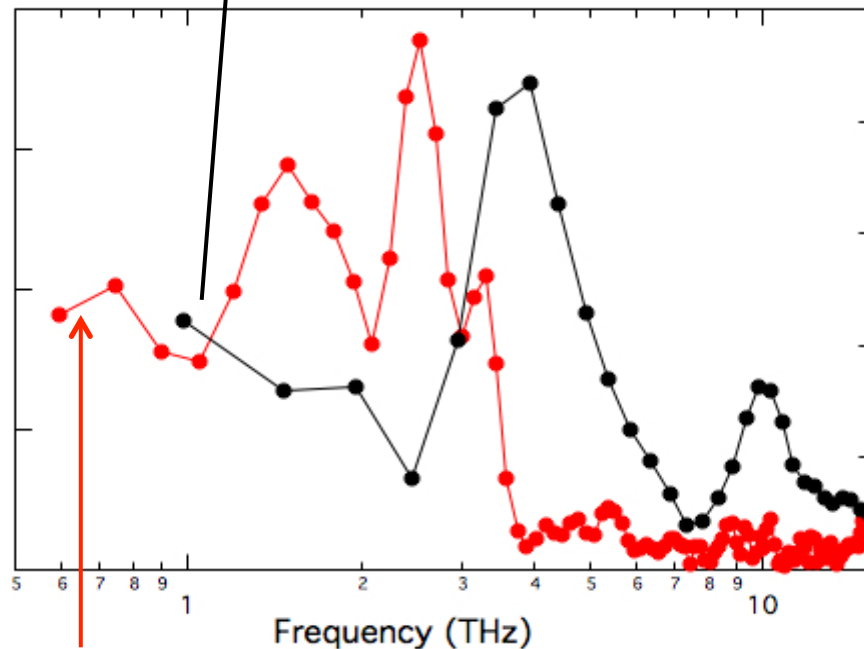
Blue: as expected at the entrance of FEL1  
 Red: predicted at TeraFERMI extraction point (FEL Off)  
 Green: predicted at TeraFERMI extraction point (FEL On)



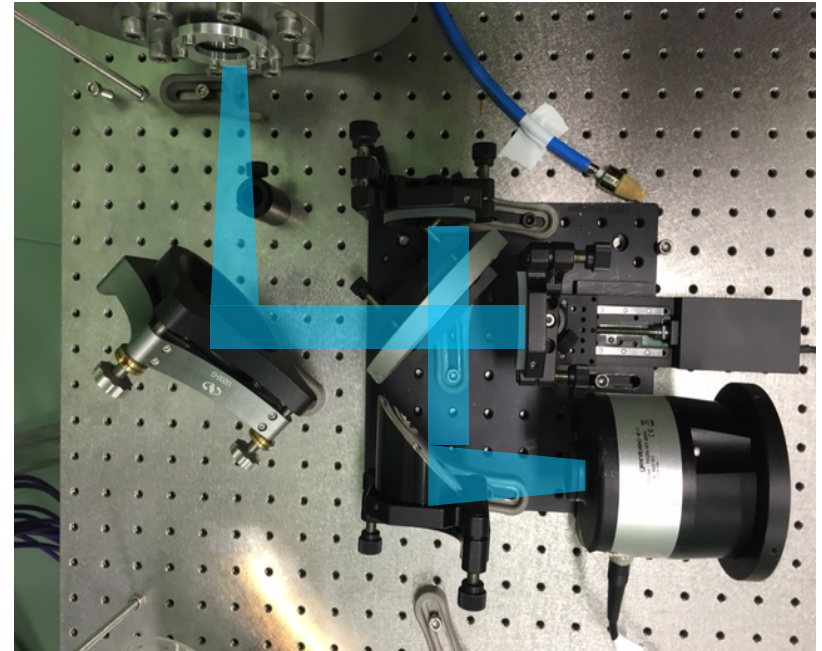
# Integrated power



TeraFERMI commissioning shift  
(March 2016)



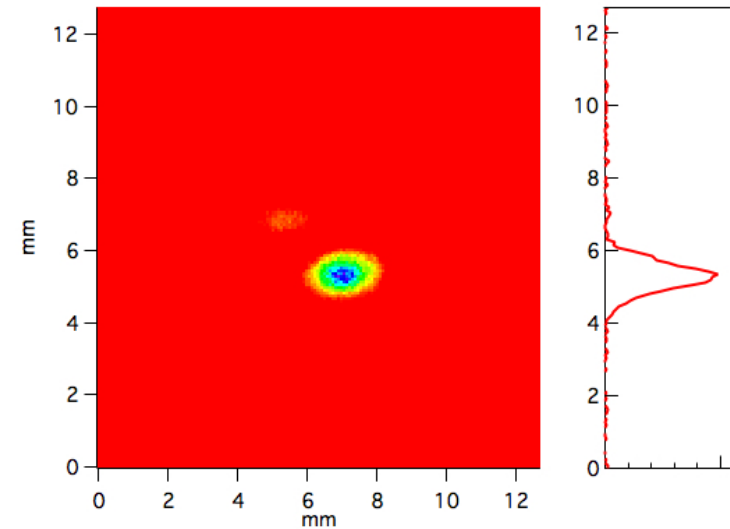
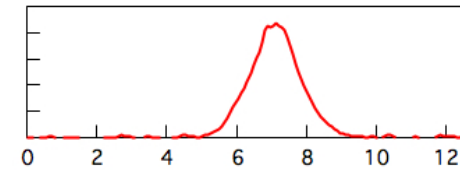
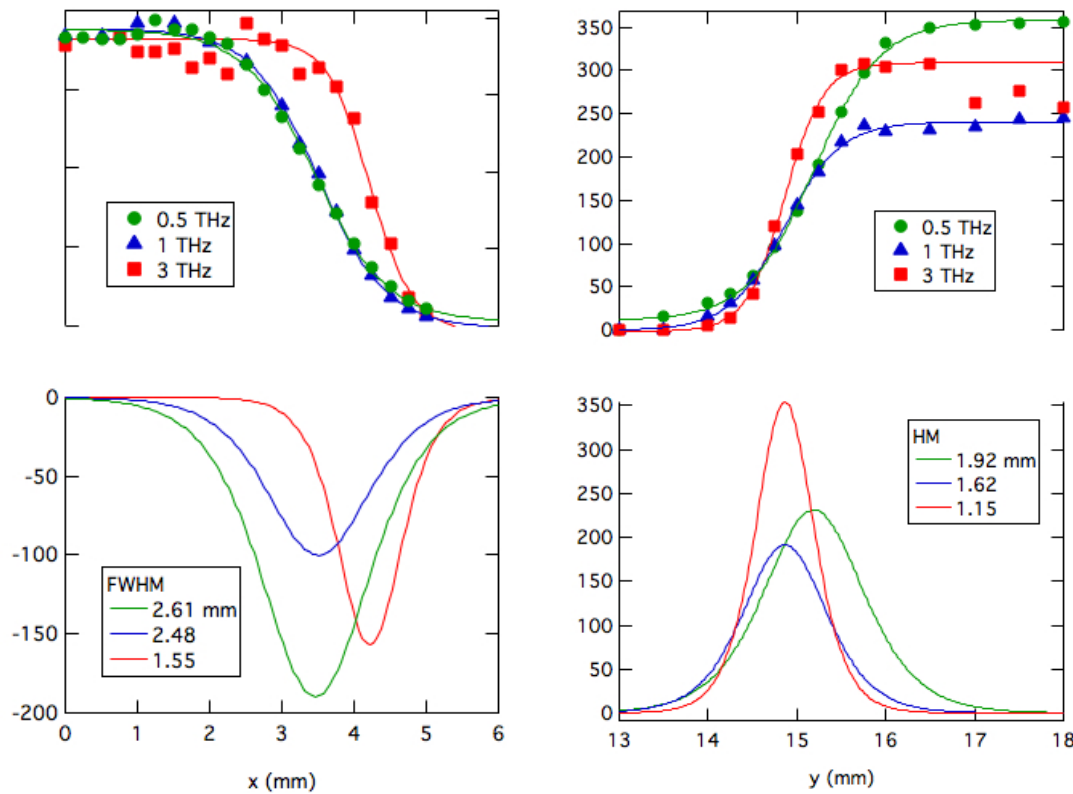
e-beam optimized for FEL users,  
flat current profile at the undulator  
(April 2016)



$\Delta L = 0.3 \text{ mm} \rightarrow \Delta\omega_{\text{res}} = 0.5 \text{ THz}$   
 $\delta L = 3 \text{ }\mu\text{m} \rightarrow N = 100 \text{ pts}$   
 30 averages for each point  
 1 Spectrum in  $\sim 5$  minutes @ 10Hz



For 10  $\mu\text{J}/\text{pulse}$   
~MV/cm

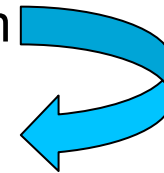


THz beam profile at  
sample position  
performed with the  
help of a **Pyrocam**  
**IIIHR** camera.

# Conclusions

- ✓ Infrared data show that the **LNO/LMO SLs** display the presence of significant mid-infrared excitations that are not present in LNO or LMO alone
- ✓ Interfacial charge redistribution is identified as the origin of changes in the MIR spectral response of LNO/LMO **at variance with LNO thin films**
- ✓ LNO heterostructures are a great platform to manipulate the interplay of electronic magnetic and vibrational degrees of freedom

opportunity to **THz control of matter @TeraFERMI**

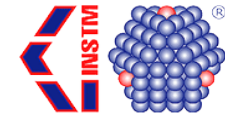


## Perspectives @TeraFERMI

- Synchronizing an external laser source
  - Electro-optic sampling
- THz pump - NIR probe (780 and 1560 nm)

# Acknowledgments

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F. Giorgianni



### **Temple University**

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M. Golalikhani



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P. Orgiani







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Thank you!

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